

UCC28221 200-W Evaluation Module (EVM)



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Exceeding the specified input range may cause unexpected operation and/or irreversible damage to the EVM. If there are questions concerning the input range, please contact a TI field representative prior to connecting the input power.

Applying loads outside of the specified output range may result in unintended operation and/or possible permanent damage to the EVM. Please consult the EVM User's Guide prior to connecting any load to the EVM output. If there is uncertainty as to the load specification, please contact a TI field representative.

During normal operation, some circuit components may have case temperatures greater than 50°C. The EVM is designed to operate properly with certain components above 50°C as long as the input and output ranges are maintained. These components include but are not limited to linear regulators, switching transistors, pass transistors, and current sense resistors. These types of devices can be identified using the EVM schematic located in the EVM User's Guide. When placing measurement probes near these devices during operation, please be aware that these devices may be very warm to the touch.

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System Power

ABSTRACT

The UCC28221 EVM is a 200-W power converter that converts 36-V to 76-V dc input voltage to a regulated 12-V dc output in a two-channel interleaved forward converter topology.

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1 Introduction

The UCC28221 control device from Texas Instruments is used in a dual interleaved forward converter that enables the power supply designer to reduce output current ripple and reduce magnetic size per power stage allowing for improved transient response. The UCC28221 is a dual interleaved PWM controller with programmable maximum duty cycle per channel up to 90% for interleaved forward and interleaved flyback designs.

The power module has two isolated 100-W forward power stages operating at 500 kHz, which are operating 180 degrees out of phase with each other. This allows for smaller magnetic design and ripple current cancellation on the output. The ripple current cancellation on the output allows for a larger allowable equivalent series resistance (ESR) in your output capacitance.

The converter design also takes advantage of the on board 110-V internal JFET start up circuit of the UCC28221 that removes the need of an external trickle charge resistor for boot strapping. This circuit turns off after auxiliary power is supplied to the device conserving power. This saves the power supply designer one component and in high volume applications could be a considerable cost savings.

To correctly operate this EVM requires a minimum load of 50 W and a fan to keep the ambient temperature at or below 40°C. Not keeping the EVM's ambient temperature at or below 40°C could damage the EVM.

2 Caution

High voltage levels are present on this evaluation module whenever it is energized. Proper safety precautions must be taken when working with this power module. Before handling, power must be removed from the EVM and the input storage capacitance must be discharged below 50 V.



Figure 1. Typical Application Schematic

3 **Electrical Characteristics**

| Та | able 1. | | | |
|-----------------|---------|-----|------|-------|
| | MIN | ТҮР | MAX | UNITS |
| V _{IN} | 36 | 48 | 76 | |
| Output | 11.4 | 12 | 12.6 | V |
| Pout | 50 | | 200 | W |
| Output ripple | | | 500 | mV |

Performance 4



Figure 2





5 Layout



Figure 8. Top View



Figure 9. Bottom View

C1, C6

6 List of Materials

The EVM list of materials is shown in Table 1.

| Table 2. Evaluation module List of materials (In A000) | | | | | | |
|--|-----|---|--------------|------------------|--|--|
| REFERENCE | QTY | DESCRIPTION | MANUFACTURER | PART NUMBER | | |
| C6 | 2 | Capacitor, ceramic, 1.0 µF, 16 V, X7R, 10%, 805 | Std | Std | | |
| C12 | 2 | Capacitor ceramic 47 pE 50 V X7B 5% 603 | Komot | C0603C470 I5GACT | | |

Table 2. Evaluation Module List of Materials (HPA035)

| C11, C12 | 2 | Capacitor, ceramic, 47 pF, 50 V, X7R, 5%, 603 | Kemet | C0603C470J5GACTU |
|---------------------------------|---|---|-------------------------|-----------------------------|
| C13, C15 | 2 | Capacitor, tantalum Chip, 47 μF, 16 V, 0.281 x 0.126 | Vishay | 595D476X9016C2T |
| C17, C18, C19, C20, C21, C22 | 6 | Capacitor, ceramic, 1000 pF, 200 V, X7R, 10%, 1206 | Vishay | VJ1206Y102KXCA |
| C2 | 1 | Capacitor, ceramic,0.47 µF, 50 V, X5R, 10%, 603 | AVX | 06036D474KAT |
| C23 | 1 | Capacitor, ceramic, 0.01 μF , 500 V, X7R, 10%, 1206 | Vishay | VJ1206Y103KXEA |
| C24, C26, C27 | 3 | **Capacitor, OS-CON, 82 μF , 16 V, 40 mΩ, 20%, 8.3mm (E7) | Sanyo | 16SVP82M |
| C28 | 1 | Capacitor, ceramic, 0.01 μF , 25 V, X7R, 10%, 603 | Kemet | C0603C104K3RACTU |
| C29 | 1 | Capacitor, ceramic, 680 pF, 16 V, X7R, 10%, 603 | Std | Std |
| C3 | 1 | Capacitor, ceramic,180 pF, 50 V, X7R, 10%, 603 | Std | Std |
| C30 | 1 | Capacitor, ceramic, 1 μF , 50 V, X7R, 20%, 1210 | Std | Std |
| C31 | 1 | Capacitor, ceramic, 0.056 µF, 16 V, X7R, 10%, 603 | Std | Std |
| C32 | 1 | Capacitor, ceramic, 0.1 $\mu\text{F},$ 50 V, X7R, 20%, 1210 | Std | Std |
| C33 | 1 | Capacitor, ceramic, 0.47 µF, 16 V, X7R, 10%, 1206 | Vishay | VJ1206Y474KXJA |
| C4, C14, C16 | 3 | **Capacitor, MLP, 4.0 μF, 100 V | ITW PAKTRON | 405K100CS4G |
| C5, C25 | 2 | Capacitor, ceramic, 4.7 μF, 25 V, X7R, 10%, 1210 | Vishay | Std |
| C7, C9 | 2 | Capacitor, ceramic, 0.1 μF , 25 V, X7R, 10%, 603 | Kemet | C0603C104K3RACTU |
| C8, C10 | 2 | Capacitor, ceramic, 56 pF, 50 V, NPO, 5%, 603 | Std | Std |
| D1, D2, D13 | 3 | Diode, switching, 200 mA, 200 V, 330 mW, SOT23 | Zetex | BAS21 |
| D12 | 1 | Diode, zener, 9.1 V, 350 mW, SOT23 | Diodes, Inc. | BZX84C9V1T |
| D3 | 1 | Diode, zener, 15 V, 350 mW, SOT-23 | Diodes, Inc. | BZX84C15 |
| D4, D5, D6, D7 | 4 | Diode, schottky, 500 mA, 30 V, SOD123 | ON Semiconductor | MBR0530 |
| D8, D9, D10, D11 | 4 | Diode, dual schottky, 20 A, 100 V, D2PAK/HS | International Rectifier | MBRB20100CTTRL |
| HS1, HS2, HS3, HS4, HS5, HS6 | 6 | **Heatsink, surface mount heat sink, D2pak | Aavid | 573300 |
| J1, J2 | 2 | Terminal block, 4 pin, 15 A, 5.1 mm, 0.80 x 0.35 | OST | ED2227 |
| L1 | 1 | **Inductor, SMD, 470 μH, 62 mA, 26 mΩ, 0.177 x 0.126 | TDK | NL453232T-471J |
| L2, L3 | 2 | **Inductor, SMT, 3.2 $\mu H,$ 18 $A_{RMS},$ 6.8 m $\Omega,$ 0.51 x 0.51 | | IHLP-5050FD- RZ-3R3-M-01 |
| Q1, Q2 | 2 | MOSFET, N-channel, 200 V, 0.030 Ω, D2PAK/HS | VISHAY | SUM65N20-30 |
| | | | | |



| REFERENCE | QTY | DESCRIPTION | MANUFACTURER | PART NUMBER |
|---|-----|---|-------------------|---------------|
| R1 | 1 | Resistor, chip, 15.0 kΩ, 1/10 W, 1%, 805 | Panasonic | ERJ-6ENF1502V |
| R12, R14 | 2 | Resistor, chip, 1 kΩ, 1/16 W, 1%, 603 | Panasonic | ERJ-3EKF1001V |
| R13, R15 | 2 | Resistor, chip, 5.23 Ω, 1/8 W, 1%, 1206 | Std | Std |
| R16, R17 | 2 | Resistor, chip, 100 Ω, 1/10 W, 1%, 805 | Std | Std |
| R18, R19 | 2 | Resistor, chip, 5.23 Ω, 1/10 W, 1%, 805 | Std | Std |
| R2 | 1 | Resistor, chip, 22.6 kΩ, 1/10 W, 5%, 805 | Std | Std |
| R20, R21 | 2 | Resistor, chip, 0 Ω, 1/10 W, 5%, 805 | Std | Std |
| R22, R23 | 2 | Resistor, chip, 10 kΩ, 1/10 W, 1%, 805 | Std | Std |
| R25, R26, R27, R28, R29, R30, R31, R32 | 8 | Resistor, chip, 7.5 Ω, 1 W, 5%, 2512 | Std | Std |
| R3 | 1 | Resistor, chip, 604 kΩ, 1/10 W, 1%, 805 | Panasonic | ERJ-6ENF6043V |
| R33, R34 | 2 | Resistor, chip, 499 Ω, 1/8 W, 1%, 1206 | Panasonic | |
| R35 | 1 | Resistor, chip, 3.57 kΩ, 1/16 W, 1%, 603 | Std | Std |
| R36 | 1 | Resistor, chip,5.23 kΩ, 1/16 W, 1%, 603 | Std | Std |
| R37 | 1 | Resistor, chip, 1.37 kΩ, 1/16 W, 1%, 603 | Std | Std |
| R38 | 1 | Resistor, chip, 100 kΩ, 1/16 W, 1%, 603 | Std | Std |
| R4 | 1 | Resistor, chip, 20.0 Ω, 1/8 W, 1%, 1206 | Panasonic | ERJ-8ENF10R0V |
| R5 | 1 | Resistor, chip, 24.9 kΩ, 1/10 W, 1%, 805 | Panasonic | ERJ-6ENF2492V |
| R6, R24 | 2 | Resistor, chip, 750 Ω, 1/16 W, 1%, 603 | Std | Std |
| R7 | 1 | Resistor, chip, 15.4 kΩ, 1/10 W, 1%, 805 | Std | Std |
| R8 | 1 | Resistor, chip, 976 kΩ, 1/10 W, 1%, 805 | Panasonic | ERJ-6ENF9763V |
| R9 | 1 | Resistor, chip, 5.36 kΩ, 1/10 W, 1%, 805 | Std | Std |
| T1, T2 | 2 | **Transformer, current sense, 10 A, 500 kHz, 1:50, 0.330 x 0.360 | Pulse | P8205T |
| T3, T4 | 2 | **SMT transformer, 2 Primary, 1 Secondary, 500 kHz, 103 W, L _{MAG} = 35 μH, 0.787 x 0.984 | Payton | 50863 |
| TP1 | 1 | Adaptor, 3.5 mm probe clip (or 131-5031-00), 0.2 | Tektronix | 131-4244-00 |
| U1 | 1 | Dual Interleaved PWM Controller With Programmable Max Duty Cycle, SO16 | ТІ | UCC28221D |
| U2 | 1 | High Speed Low Side Power MOSFET Driver, SO8 | Texas Instruments | UCC27324D |
| U3 | 1 | Optocoupler, SO8 | Motorola | MOC206 |
| U4 | 1 | Adj Shunt Regulator, 100 mA, 36 V, SO8 | ТІ | TL431AID |
| | 1 | PCB, 0 ln x 0 ln x 0 ln | Any | HPA035 |

NOTES: (1). These assemblies are ESD sensitive, ESD precautions shall be observed.

(2). These assemblies must be clean and free from flux and all contaminants. Use of no clean flux is not acceptable.

(3). These assemblies must comply with workmanship standards IPC-A-610 Class 2.

(4). Reference designators marked with an asterisk ('**') cannot be substituted. All other components can be substituted with equivalent MFG's components.

7 References

Datasheet, UCC28220/1 Dual Interleaved PWM Controller with Programmable Maximum Duty Cycle, TI Literature No. SLUS544